NSN 5961-01-276-1193

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-276-1193 **Inclosure Material:** Metal **Overall Length:** 0.190 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.219 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor **Current Rating Per Characteristic:** 500.00 microamperes zero-gate-voltage drain current all transistor **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation all transistor **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: